

DIO1005

Ultra Low On-Resistance Dual, SPDT Analog Switch

Features

- Switch Type: SPDT(2X)
- Voltage Operation: 1.8V to 4.3V
- Ultra-Low On Resistance: 0.75Ω @ +4.3V
- -3dB Bandwidth: 75MHz
- High Off-isolation: -78dB@100kHz
- Low Crosstalk: -100dB@100kHz
- Excellent On Resistance Matching: 0.03Ω
- Low Total Harmonic Distortion (THD)
- Rail-to-Rail Input and Output Operation
- Break-Before-Make Switching
- Green Packaged:DFN3*3-10 and MSOP-10
- 8kV HBM ESD

Applications

- Cell-Phone/PDA
- MP3/MP4/PMP
- Portable Instrumentation
- Battery Powered Communications
- Computer Peripherals

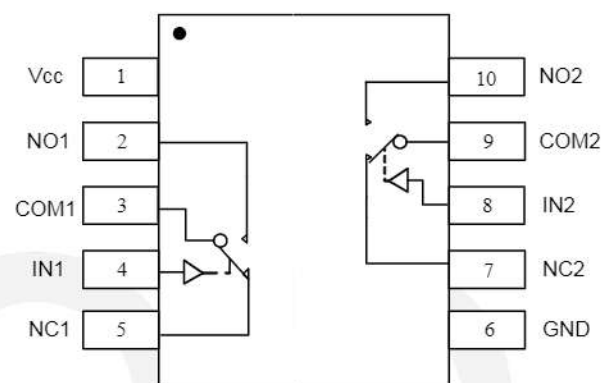
Descriptions

The DIO1005 is a dual Single-Pole, Double-Throw (SPDT) analog switch. DIO1005 operates from a single 1.8V to 4.3V supply and features an ultra-low on resistance of 0.75Ω at a +4.3V supply and $T_A = 25^\circ\text{C}$. This device is fabricated with sub-micron CMOS technology to achieve fast switching speeds and is designed for break-before-make operation.

DIO1005 guarantees 0.03Ω on-resistance matching between switches, on-resistance flatness over the signal range, high off-isolation and low crosstalk, which ensures excellent linearity and low distortion when switching audio signals. DIO1005 consists of two normally open and two normally close switches.

DIO1005 provides packages with Green DFN3*3-10 and MSOP-10.

Block Diagram



Ordering Information

Order Part Number	Top Marking		T_A		Package
DIO1005DN10	D1005	Green	-40 to +85°C	DFN-10	Tape & Reel, 5000
DIO1005MP10	DIO1005	Green	-40 to +85°C	MSOP-10	Tape & Reel, 3000

Pin Assignment

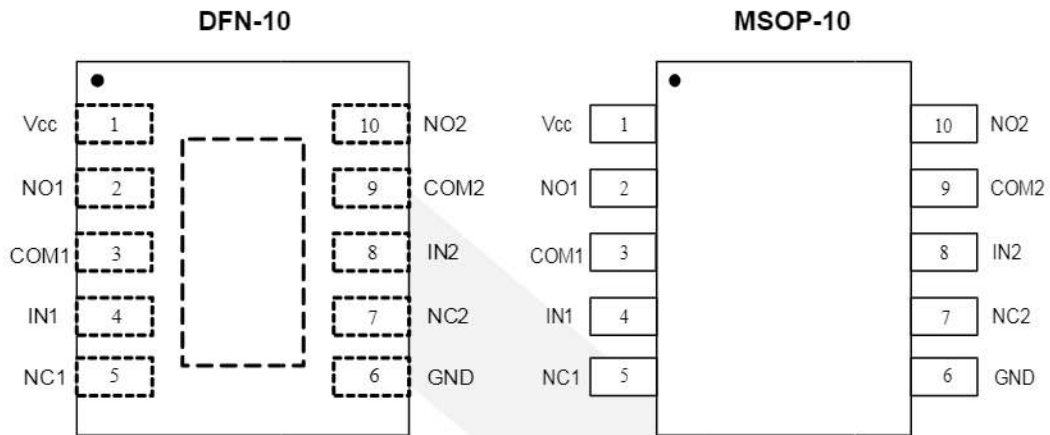


Figure 1 Top View

Pin Descriptions

Pin Name	Description
V _{CC} /GND	Power Supply
IN1, IN2	Digital control pin to connect the COM terminal to the NO or NC terminals
COM1, COM2	Common terminal
NO1, NO2	Normally-open terminal
NC1, NC2	Normally-closed terminal

Truth Table

IN1, IN2	NO	NC
L	OFF	ON
H	ON	OFF



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Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Symbol	Parameter	Min.	Max.	Unit
V_{CC}	Supply Voltage	-0.3	+4.6	V
V_{CNTRL}	DC input Voltage	-0.3	$(V_{CC}) + 0.3$	V
V_{SW}	DC input I/O Voltage	-0.3	$(V_{CC}) + 0.3$	V
I_{IK}	DC input Diode current		-50	mA
T_{STG}	Storage Temperature	-65	+150	°C
ESD	HBM, JEDEC: JESD22-A114		8000	V

Recommend Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended Operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not Recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V_{CC}	Supply voltage	1.8	4.3	V
V_{CNTRL}	Control input voltage (IN1/IN2)	0	V_{CC}	V
V_{SW}	Switch I/O voltage	0	V_{CC}	V
T_A	Operating Temperature	-40	85	°C



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Electrical Characteristics

All typical value are at $V_{CC}=4.3V$, $GND=0V$, $V_{IH}=1.6V$, $V_{IL}=0.5V$, $T_A=25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	V_{CC}/V	Temp	Min	Typ	Max	Unit
Analog Switch Characteristics								
R_{ON}	On-Resistance	V_{NO}, V_{NC} , or $V_{COM}=1V$, $I_{COM} = -100mA$	4.3	+25°C		0.75	0.85	Ω
				-40 to 85°C			0.95	Ω
ΔR_{ON}	On-Resistance Match Between Channels	V_{NO}, V_{NC} or $V_{COM}=1V$, $I_{COM} = -100mA$	4.3	+25°C		0.03	0.15	Ω
				-40 to 85°C			0.20	Ω
$R_{FLAT(ON)}$	On-Resistance Flatness	V_{NO}, V_{NC} or $V_{COM}=1V, 2.5V$ $I_{COM} = -100mA$	4.3	+25°C		0.15	0.23	Ω
				-40 to 85°C			0.30	Ω
$I_{NC(OFF)}$, $I_{NO(OFF)}$	Source OFF Leakage Current	$V_{NO}, V_{NC}=3.3V, 0.3V$ $V_{COM}= 0.3V/3.3V$	4.3	-40 to 85°C			50	nA
$I_{NC(ON)}$, $I_{NO(ON)}$, $I_{COM(ON)}$	Channel ON Leakage Current	$V_{NO}, V_{NC}=3.3V, 0.3V$ or floating $V_{COM}= 0.3V/3.3V$	4.3	-40 to 85°C			50	nA
Digital Inputs								
V_{INH}	Input High Voltage			-40 to 85°C	1.6			V
V_{INL}	Input Low Voltage			-40 to 85°C			0.5	V
I_{IN}	Input Leakage Current	$V_{CC}=4.3V, V_{IN}=0V$, or 4.2V		-40 to 85°C			1	μA
Dynamic Characteristics								
t_{ON}	Turn-On Time	$V_{IN}=2.1V$ to 0V, $R_L=50 \Omega$, $C_L=35pF$, V_{NO1} or V_{NO2} or $V_{NC2}=2.1V$,		+25°C		25		ns
t_{OFF}	Turn-Off Time	$V_{IN}=2.1V$ to 0V, $R_L=50 \Omega$, $C_L=35pF$, V_{NO1} or V_{NO2} or $V_{NC2}=2.1V$,		+25°C		35		ns
t_D	Break-Before-Make Time Delay	$V_{IN}=2.1V$ to 0V, $R_L=50 \Omega$, $C_L=35pF$, V_{NO1} or V_{NO2} or $V_{NC2}=2.1V$,		+25°C		45		ns
O_{ISO}	Off Isolation	$V_{BIAS}=2.1V$, Signal=0dBm	100kHz	+25°C		-78		dB
			1MHz			-58		
X_{TALK}	Channel-to-Channel Crosstalk	$V_{BIAS}=2.1V$, Signal=0dBm	100kHz	+25°C		-100		dB
			1MHz			-75		
BW	-3dB Bandwidth	$V_{BIAS}=2.1V$, Signal=0dBm		+25°C		75		MHz
THD	Total Harmonic Distortion	f=20Hz to 20kHz, $R_L=32\Omega, V_{SW}=1V_{PP}$		+25°C		0.02		%
Q	Charge Injection Select Input to Common I/O	$V_G=0V, R_S=0 \Omega, C_L=1.0nF$		+25°C		4.0		pC
C_{ON}	Channel on Capacitance			+25°C		106		pF



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Symbol	Parameter	Conditions	V_{CC}/V	Temp	Min	Typ	Max	Unit
Power Requirements								
V_{CC}	Power Supply Range			-40 to 85°C	1.8		4.3	V
I_{CC}	Quiescent Supply Current	$V_{IN}=0V$ or V_{CC}	4.3	-40 to 85°C			500	nA
I_{OCT}	Increase in I_{CC} per Input	Input at 2.6V	4.3	-40 to 85°C			5	μA
		Input at 1.8V					10	



Test Diagrams

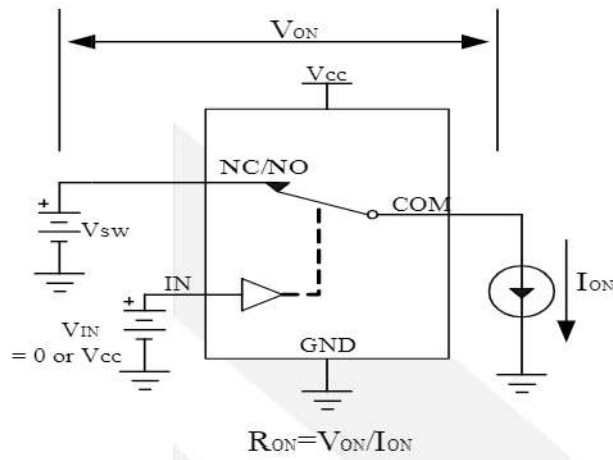


Figure 2 Switch on resistor

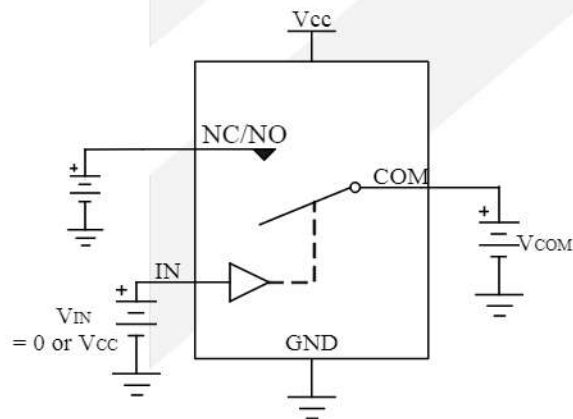


Figure 3 Switch Off Leakage

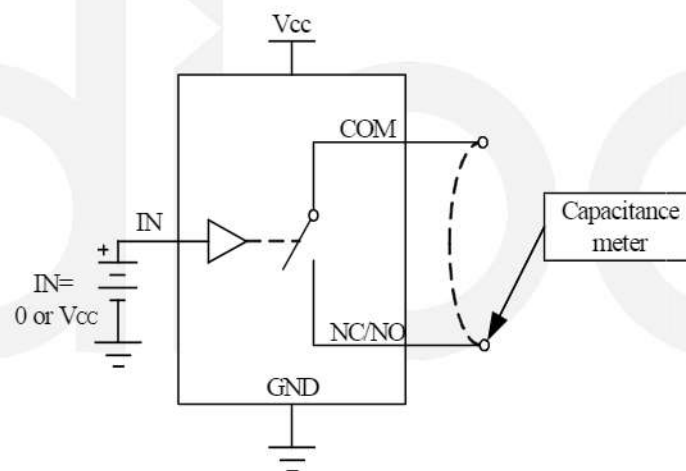


Figure 4 On/off Capacitance test

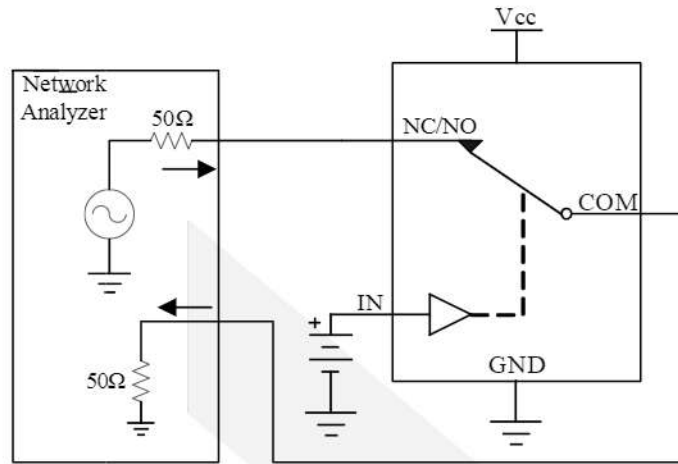


Figure 5 Bandwidth

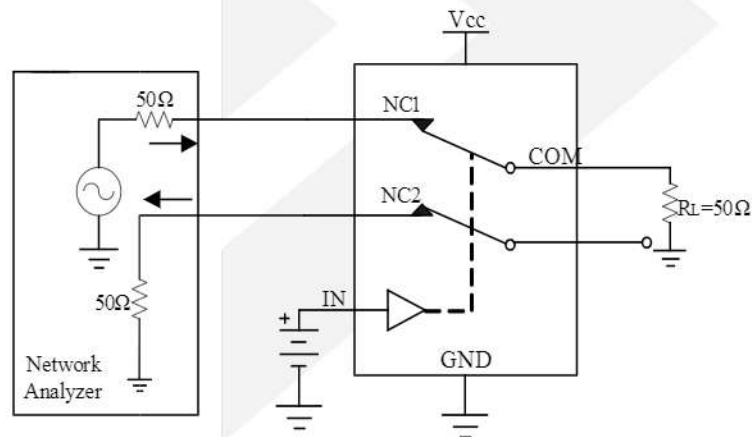


Figure 6 Channel-to-channel crosstalk

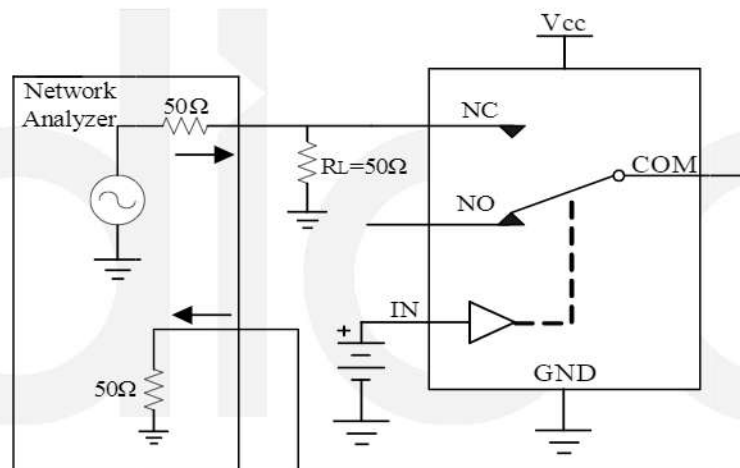


Figure 7 Off-isolation

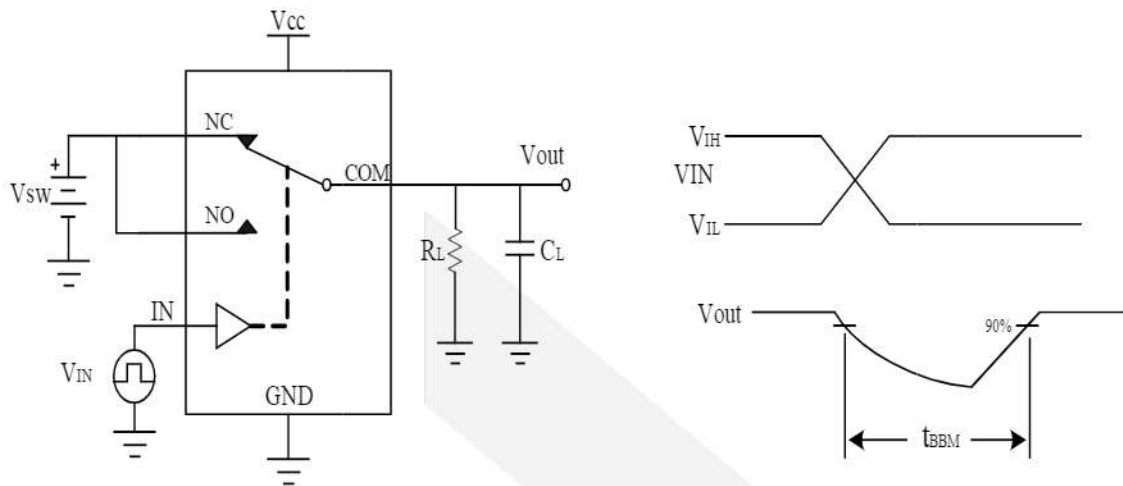


Figure 8 Break-Before-Make

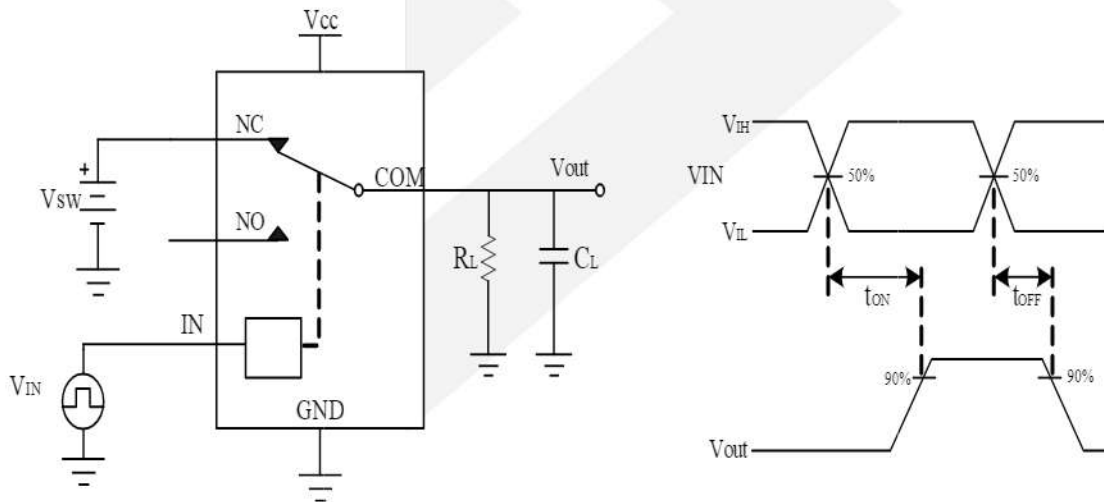


Figure 9 Turn-On/Turn-Off

CONTACT US

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